

**Cascadable Amplifier
10 to 500 MHz**

A180 / SMA180

V2

Features

- HIGH REVERSE ISOLATION: 22 dB (TYP.)
- HIGH OUTPUT POWER: +18 dBm (TYP.)

Description

The A180 RF amplifier is a discrete hybrid design, which uses thin film manufacturing processes for accurate performance and high reliability.

This single stage bipolar transistor feedback amplifier design displays impressive performance over a broadband frequency range. An active DC biasing network insures temperature-stable performance.

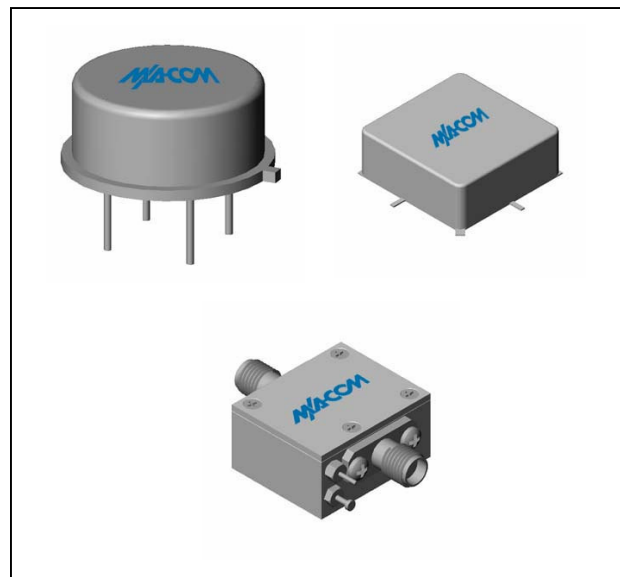
Both TO-8 and Surface Mount packages are hermetically sealed, and MIL-STD-883 environmental screening is available.

Ordering Information

Part Number	Package
A180	TO-8
SMA180	Surface Mount
CA180 **	SMA Connectorized

** The connectorized version is not RoHs compliant.

Product Image



Electrical Specifications: $Z_0 = 50\Omega$, $V_{CC} = +15 V_{DC}$

Parameter	Units	Typical	Guaranteed	
		25°C	0° to 50°C	-54° to +85°C*
Frequency	MHz	5-600	10-500	10-500
Small Signal Gain (min)	dB	16.5	16.0	15.5
Gain Flatness (max)	dB	±0.3	±0.7	±1.0
Reverse Isolation	dB	22		
Noise Figure (max)	dB	3.4	4.0	4.5
Power Output @ 1 dB comp. (min)	dBm	18.0	16.0	15.0
IP3	dBm	+33		
IP2	dBm	+45		
Second Order Harmonic IP	dBm	+51		
VSWR Input / Output (max)		1.4:1 / 1.5:1	1.9:1 / 2.1:1	2.1:1 / 2.2:1
DC Current @ 15 Volts (max)	mA	63	69	75

Absolute Maximum Ratings

Parameter	Absolute Maximum
Storage Temperature	-62°C to +125°C
Case Temperature	+125°C
DC Voltage	+17 V
Continuous Input Power	+15 dBm
Short Term Input power (1 minute max.)	100 mW
Peak Power (3 µsec max.)	0.5 W
"S" Series Burn-In Temperature (case)	+125°C

Thermal Data: $V_{CC} = +15 V_{DC}$

Parameter	Rating
Thermal Resistance θ_{jc}	45°C/W
Transistor Power Dissipation P_d	0.509 W
Junction Temperature Rise Above Case T_{jc}	+22.9°C

* Over temperature performance limits for part number CA180, guaranteed from 0°C to +50°C only.

